



# APPLICATION DATA SHEET

Electronic Version 0.0.11

Stylesheet Version: 1.0

Attorney Docket Number: 740756-2666

Publication Filing Type:

new-utility

Application Type:

utility

Title of Invention:

LASER IRRADIATION APPARATUS AND METHOD OF FABRICATING  
SEMICONDUCTOR DEVICE

## Legal Representative:

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## Foreign Priority:

2002-325383

JP 2002-11-08

Priority Claimed

Assignee (Publish): Semiconductor Energy Laboratory Co., Ltd.

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